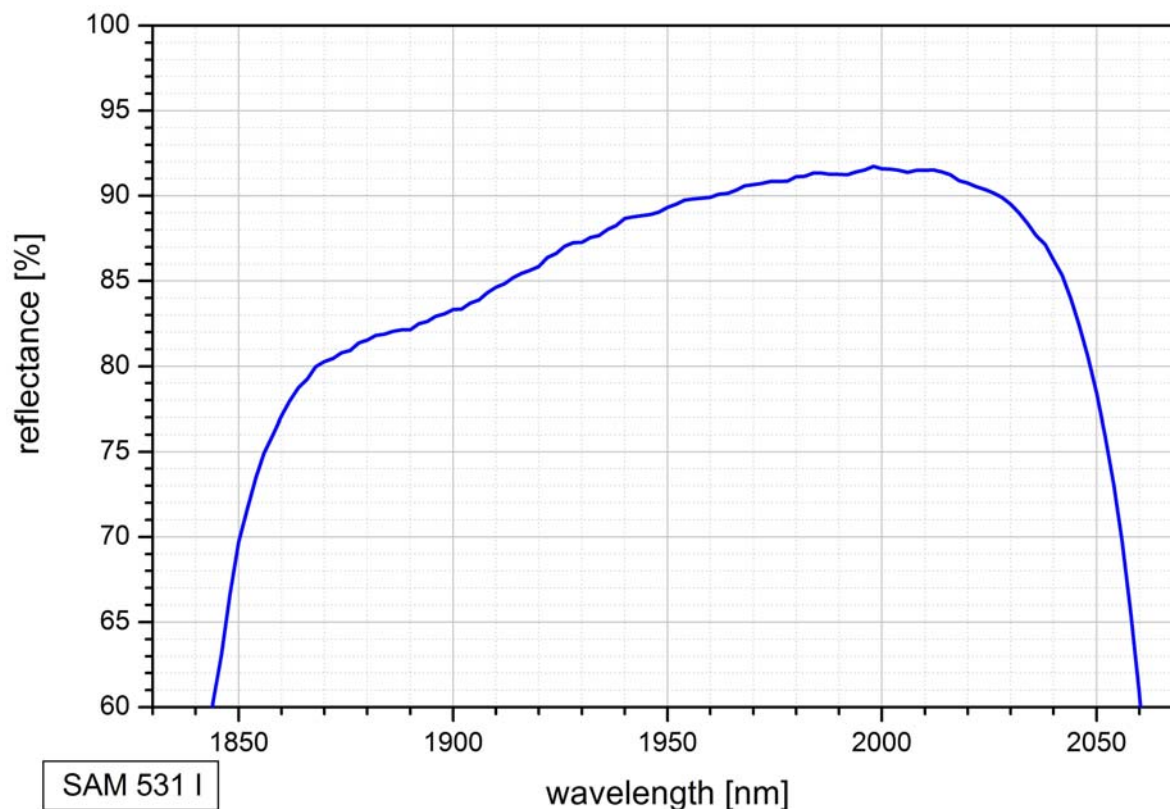


SAM™ data sheet SAM-1960-8-x-500fs, $\lambda = 1960 \text{ nm}$

Laser wavelength	$\lambda = 1960 \text{ nm}$
High reflection band (R > 90%)	$\lambda = 1950 \dots 2040 \text{ nm}$
Absorbance	$A_0 = 8 \%$
Modulation depth	$\Delta R = 5 \%$
Non-saturable loss	$A_{ns} = 3 \%$
Saturation fluence	$\Phi_{sat} = 20 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 500 \text{ fs}$
Damage threshold	$500 \text{ MW}/\text{cm}^2$
Chip area	4mm x 4mm; other dimensions on request
Chip thickness	400 μm
Protection	the SAM is protected with a dielectric front layer
Mounting of SAM-1960-8-x	denotes the type of mounting as follows:
x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance



SAM 531 I

